



# Local Made-Up and Mid Stream Contents for Crystalline Silicon PV Industry

**Chaiyuth Kiatpinyo**  
Managing Director  
Solar Synergy Co.,Ltd.

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*Glimpse of the Future: the Solar City*

# Agenda

- Understanding Silicon
- Value Chain of Crystalline Silicon PV
- Silica ( $\text{SiO}_2$ ) to Metal Grade (MG)-silicon.
- MG-Silicon to Solar Grade Silicon (SoG) Feedstock.
- SoG Feedstock to Ingot.
- Ingot to Wafer
- Wafer to Cell & down the lines
- Marketing prospect
- Q&A Session

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# Understanding Silicon

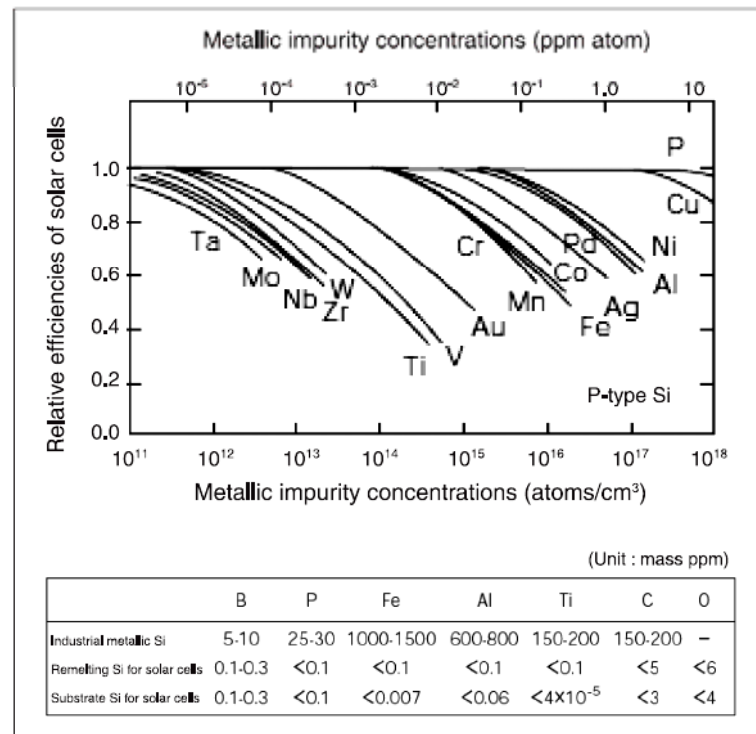
- Silicon is the second most common element on earth (after Oxygen).
- Never occurs free in nature, but only in combination with oxygen, in the form of **Quartz** rock or **Silica sand**.

	Metal Grade Silicon (MG-Si)	Solar Grade (SoG-Si)	Semiconductor Grade
% Pure Si	98.5%-99.0%	99.9999% (6N)	99.9999999%(9N)
Impurity (PPM)	15,000 – 10,000	0.5	0.0005

- **Metallurgical grade silicon (MG-Si)** – 98.5% pure silicon used in metallurgical applications.
- **Solar grade silicon (SoG-Si)** – 99.9999% pure silicon; adequately to produce Multicrystalline solar cell
- **Semiconductor Grade** – High purity silicon, usually over 99.999999% in purity; produced mainly by the capital intensive Siemens process.

# Impurities

- Impurities influencing the single crystal silicon solar cell performance and their concentrations found in various silicon raw materials.
- The primary impurities in solar silicon are **Phosphorus** and **Boron**, also with number of impurities such as Iron, Aluminium, Titanium, Carbon and Oxygen must be removed from MG-Si in order to satisfied requirements of SoG-Si.

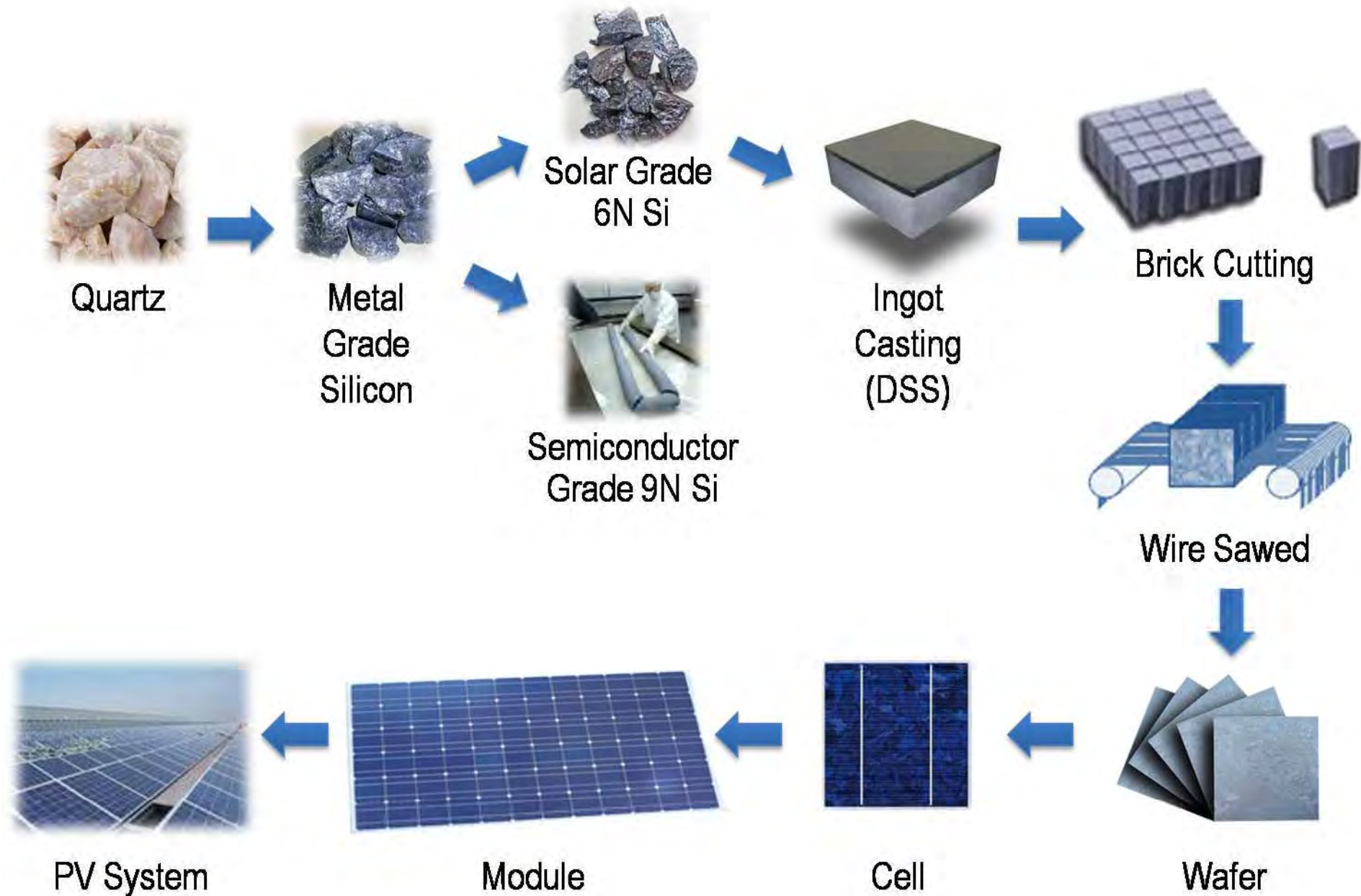


” Proceedings of the 13<sup>th</sup> IEEE Photovoltaics Specialists Conference (New York: IEEE, 1978), p.490”

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# Value Chain of Crystalline Silicon PV



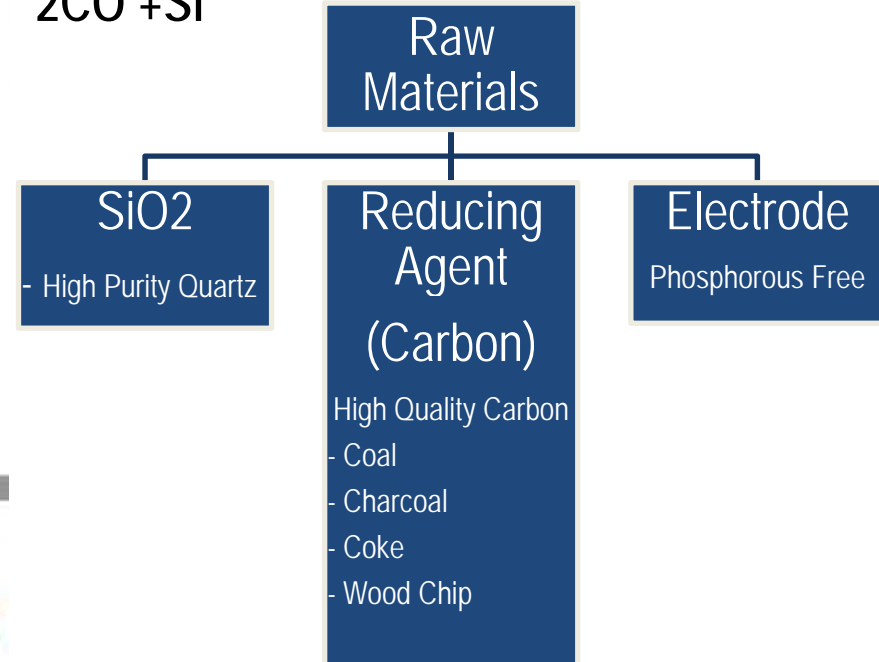
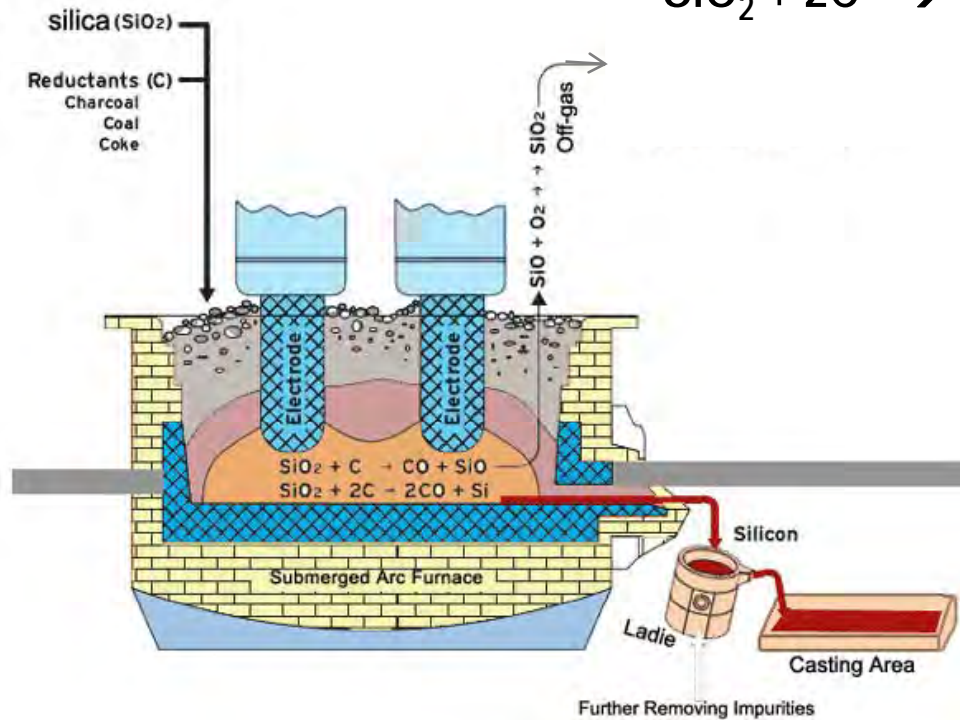
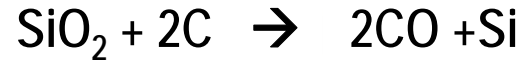


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# Refining of Quartz into Metal Grade Silicon

## Carbothermic Reduction Process



Challenges: To reduce Phosphorous (P) and Boron (B) impurities in MG-Si.

- Phosphorous including : 45% in SiO<sub>2</sub> , 45% in Carbon, 10% in Electrode
- Boron including : 39% in SiO<sub>2</sub> , 61% in Carbon

Target is to have lowest level of impurities as possible, especially for B (<7 ppmw) and P (< 25 ppmw)

# MG-Silicon to Solar Grade Silicon (SoC) Feedstock

## Impurities in MG-Si and Refining Target (ppmw)

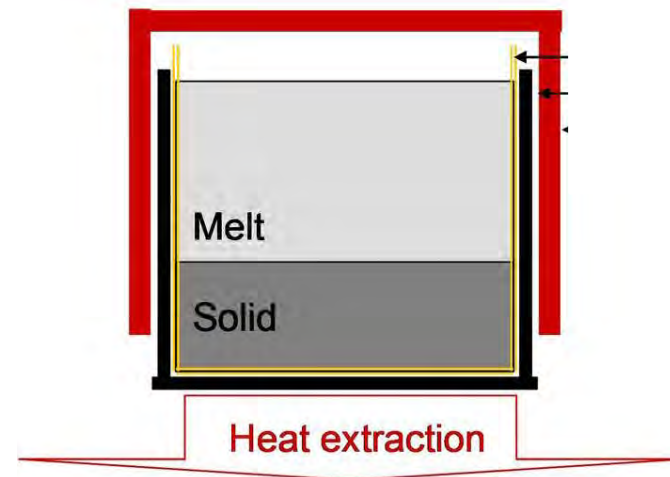
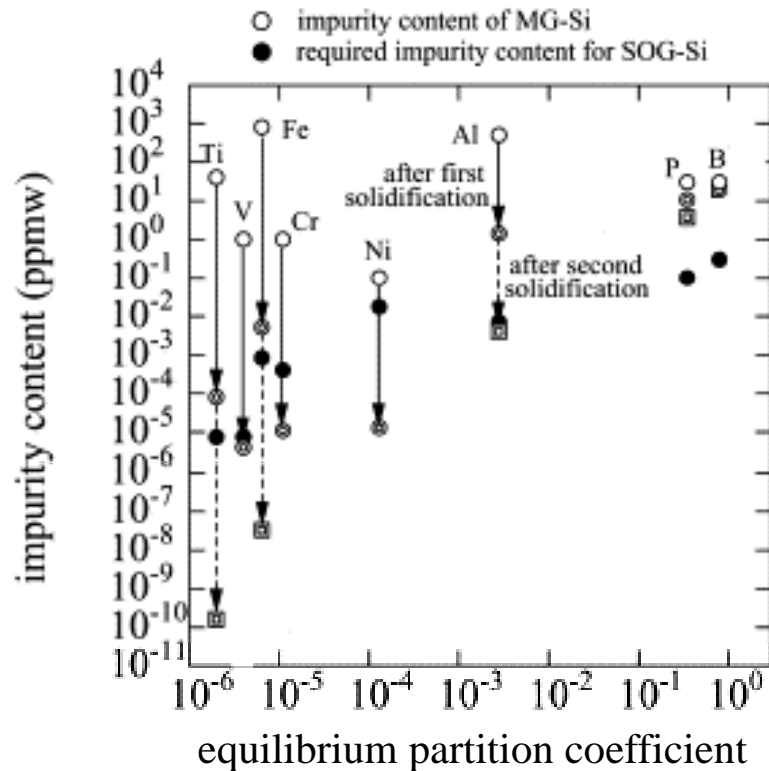
	P	B	Fe	Al	Ti	C
MG-Si	25	7	1,000	800	200	5000
SoG-Si	<0.1	0.1~0.3	<0.1	<0.1	<0.1	<0.5

Solar Synergy developed a metallurgical processes, possible to produce high-purity SoG-Si from metallurgical grade silicon.

- **Directional Solidification:** Removal of Metal Impurities in Molten Silicon.
- **Electron Beam:** Evaporation of Phosphorus in Molten Silicon in Vacuum.
- **Plasma with Reactive Gases System:** Boron Removal in Molten Silicon.

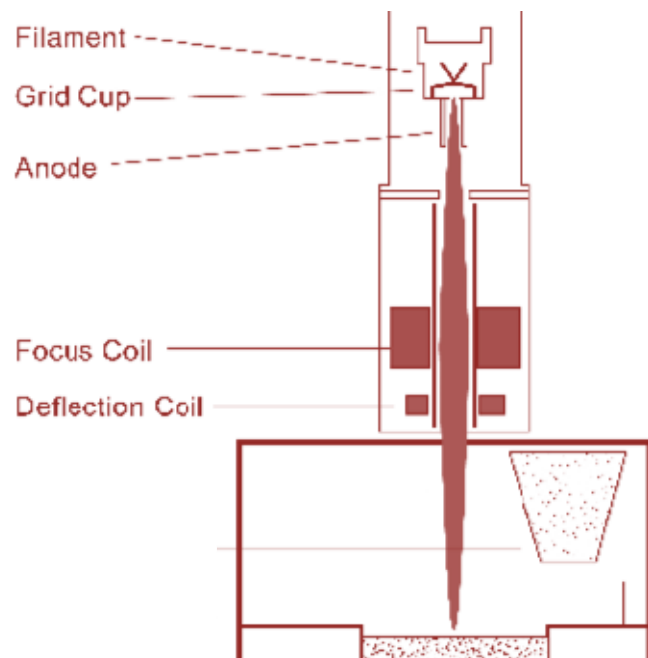
# Removal of Metal Impurities in Molten Silicon by Directional Solidification

- Effectives mean of removal metallic impurities.
- “Equilibrium partition coefficient” of metals between liquid and solid phase are small.
- Impurity with low equilibrium partition coefficient tends to stay in liquid region. For Phosphorous (0.35) and Boron (0.8) are difficult to remove.

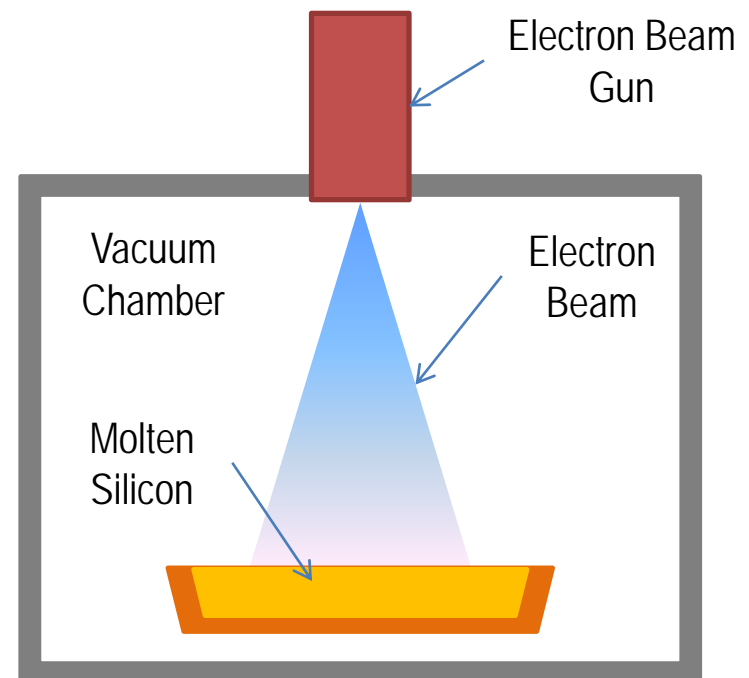


# Evaporation of Phosphorus in Molten Silicon by an Electron Beam Irradiation Method

- Equilibrium partition coefficient of Phosphorus is high (0.35), directional solidification is not effective.
- Phosphorus could be removed by evaporation, taking advantage of its high vapor pressure.
- Utilizing Electron Beam (EB) melting dephosphorisation in vacuum chamber, with proprietary technique to manipulate surface flow.

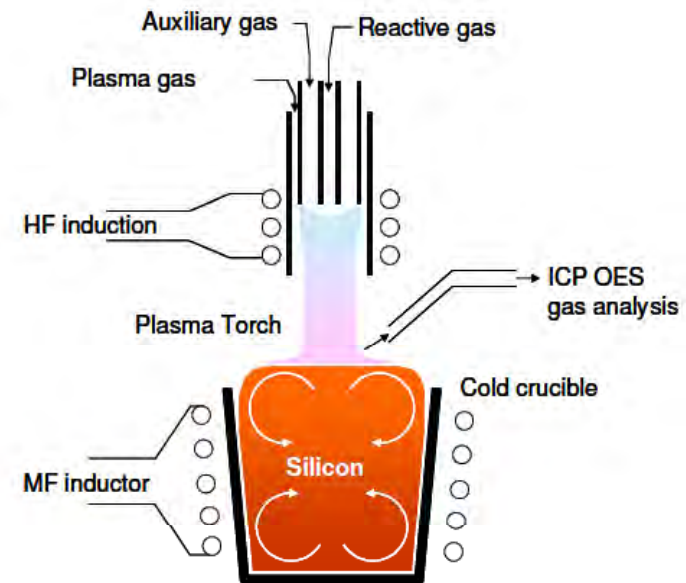
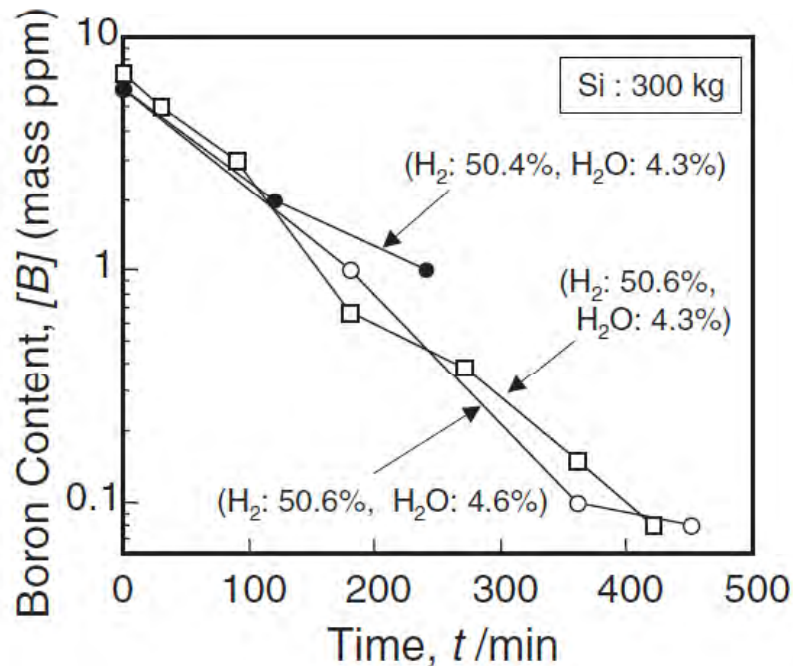


Electron Beam Gun Diagram



# Boron Removal in Molten Silicon by Steam-Added and Reaction Gases Plasma

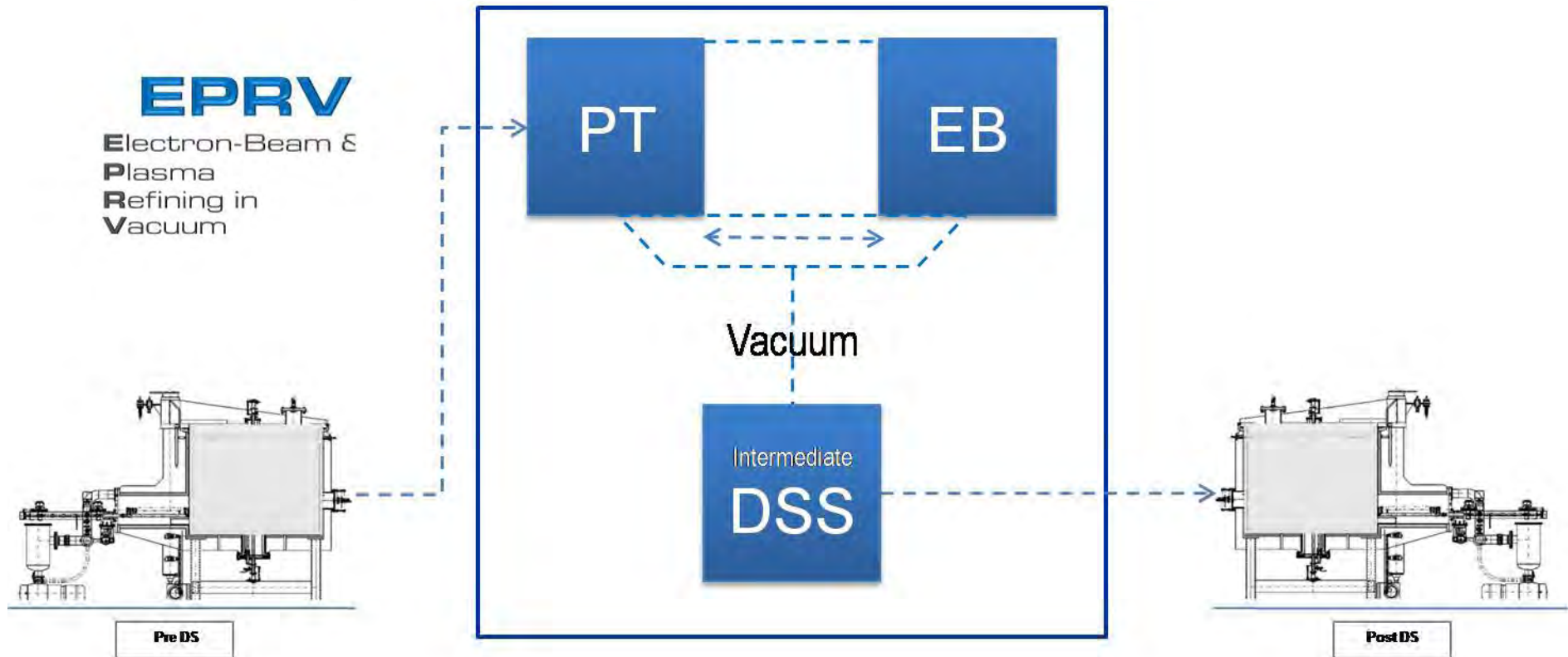
- Boron is difficult to remove by either Directional Solidification or Electron Beam Vaporization, because Equilibrium partition coefficient is at 0.8 with low vapor pressure similar to iron and titanium.
- Oxidation is possible to remove boron from molten silicon, with reactive gas plasma. Increase surface temperature by plasma heating also increase effectiveness of the process.



# MG-Silicon to Solar Grade Silicon (SoC) Feedstock

## Our Goals

Minimized Energy Consumption, Reduce Loss between Process and  
Simplifying Process Continuation, Clean & Non-toxic Processing



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# SoG Feedstock to Ingot

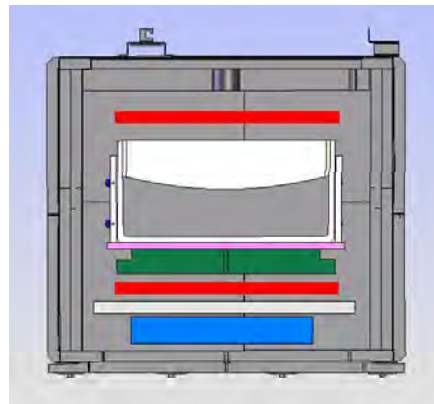
- Directional Solidification System (DSS) are stand-alone furnaces for melting and crystallizing of solar-grade silicon into an ingot for subsequent processing into wafers for solar cells.
- Require large dendrite crystal of silicon. Cycle time approx. 50 hours.



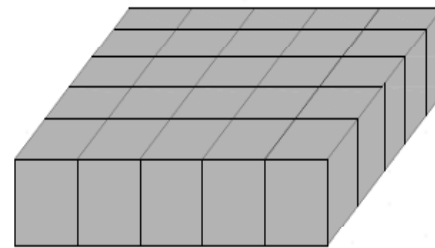
Fused Silica Crucible with  
Silicon Nitride Coating



Crucible Filled with Solar  
Grade Silicon Feed Stock



DSS with 2 Sided Heaters  
Top and Bottom



Gen 5: 5x5 Bricks  
400-450 kg



Ingot



After Melting and  
Crystallization in  
Vacuum Furnace

# SoG Feedstock to Ingot – New Quasi-mono Technology

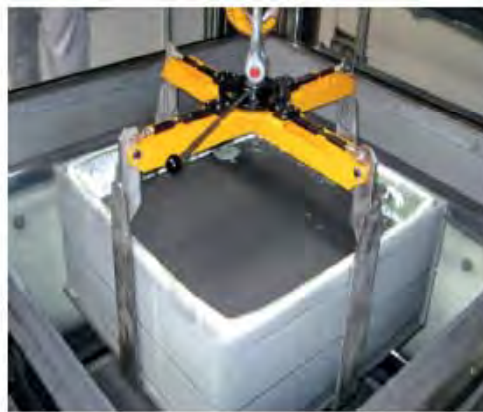
Alternative for DS Multi-Crystalline and CZ Mono-Crystalline Production

CZ process



- Higher Efficiency
- Higher Cost
- Time Consume

DS Casting



- Lower Efficiency
- Lower Cost
- Less Time Consume

Quasi-mono Technology

**“Best of Both World”**

- Production of square mono-crystalline DS ingots, wafers and cells with quality close to CZ method at cost close to DS Casting.



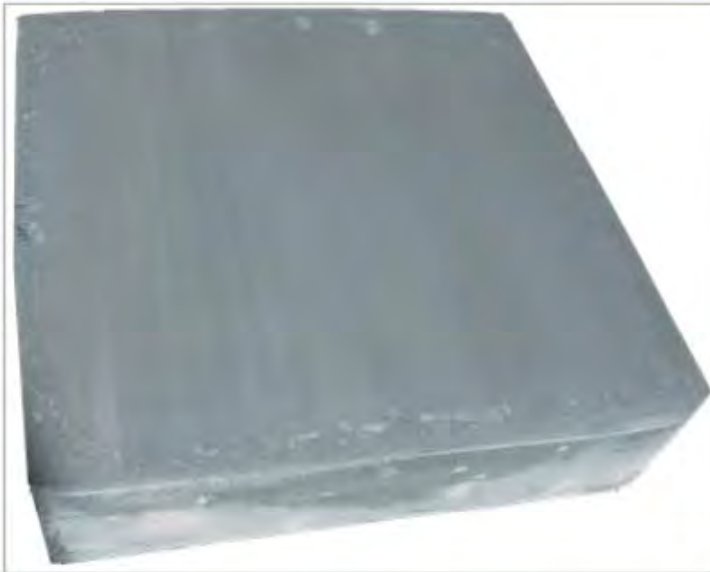
- High Efficiency
- Low Cost
- Less Time Consume



# SoG Feedstock to Ingot – New Quasi-mono Technology

## Optical Appearance of Quasi-mono Ingots

Quasi-mono Ingot



Cross Section of Gen5 Quasi-mono Ingot



Quasi-mono  
Bottom Plate



- Reproducible production of Gen5 Quasi-mono ingots
- > 80% mono-crystalline portion
- All inside brick full mono-crystalline
- Corner bricks have significant multi-crystalline domains

# SoG Feedstock to Ingot – New Quasi-mono Technology



Full mono  
Crystalline Wafer



Mono Area with  
Small Amount of  
Multicrystalline Area



Mono Area with  
Surrounding  
Multicrystalline Area



Classic  
Multicrystalline  
Wafer



Quasi-mono Crystalline Wafer

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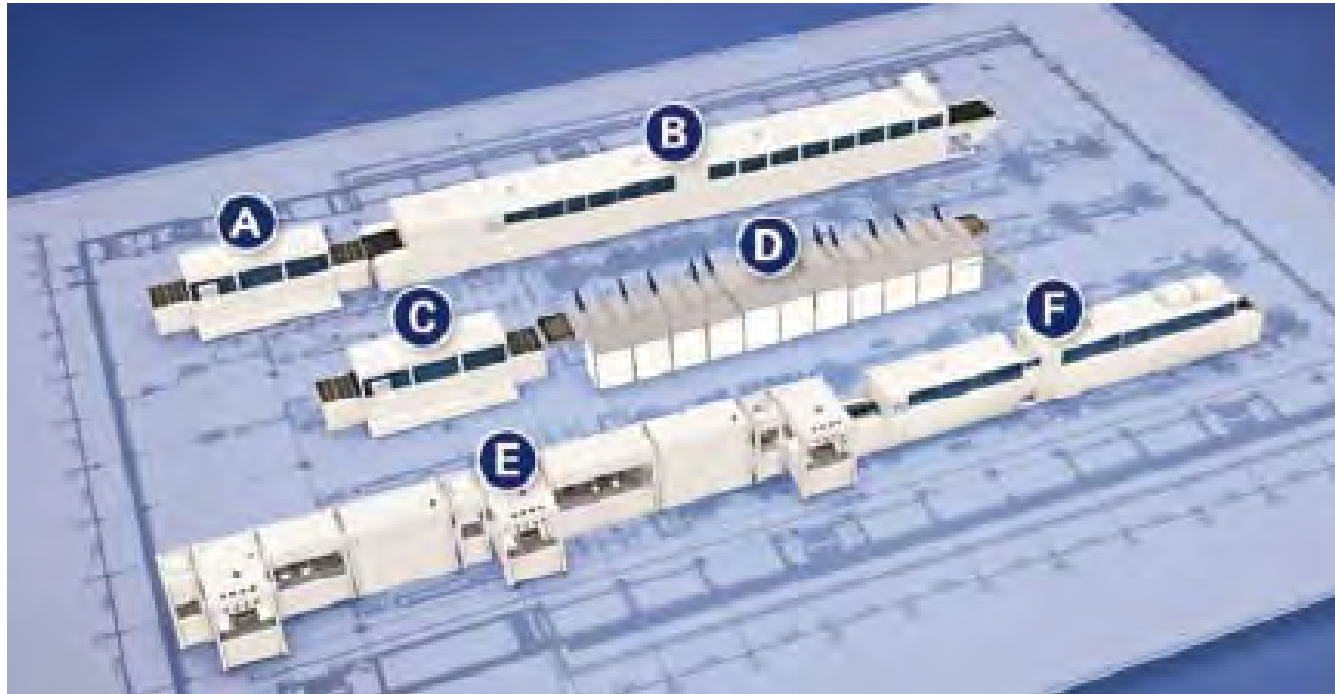
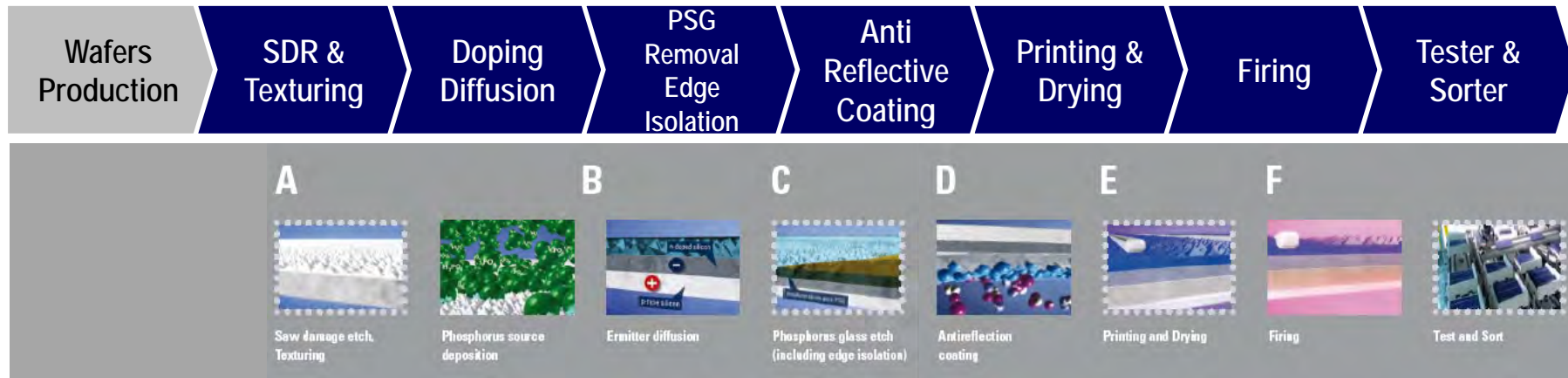
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# Wafer to Cell & down the lines Wafer Line

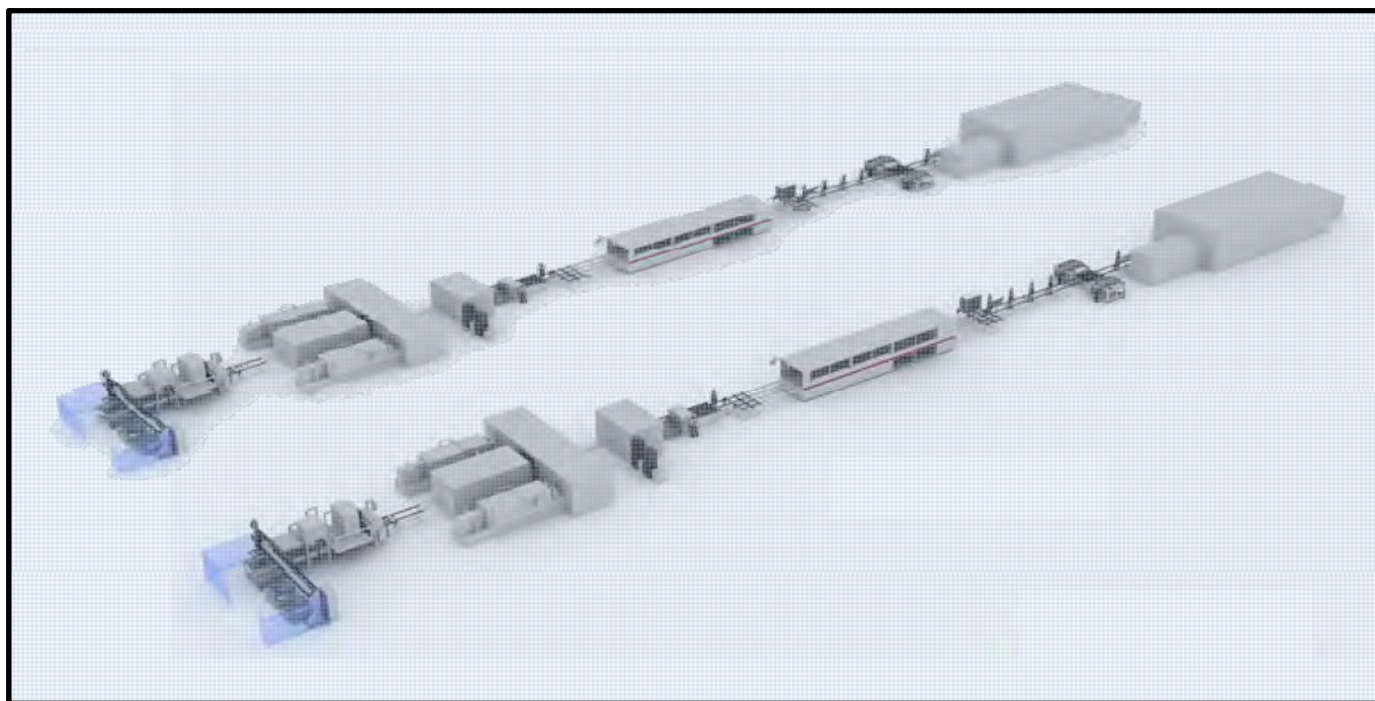


# Wafer to Cell & down the lines

## Cell Line



# Wafer to Cell & down the lines Module Line



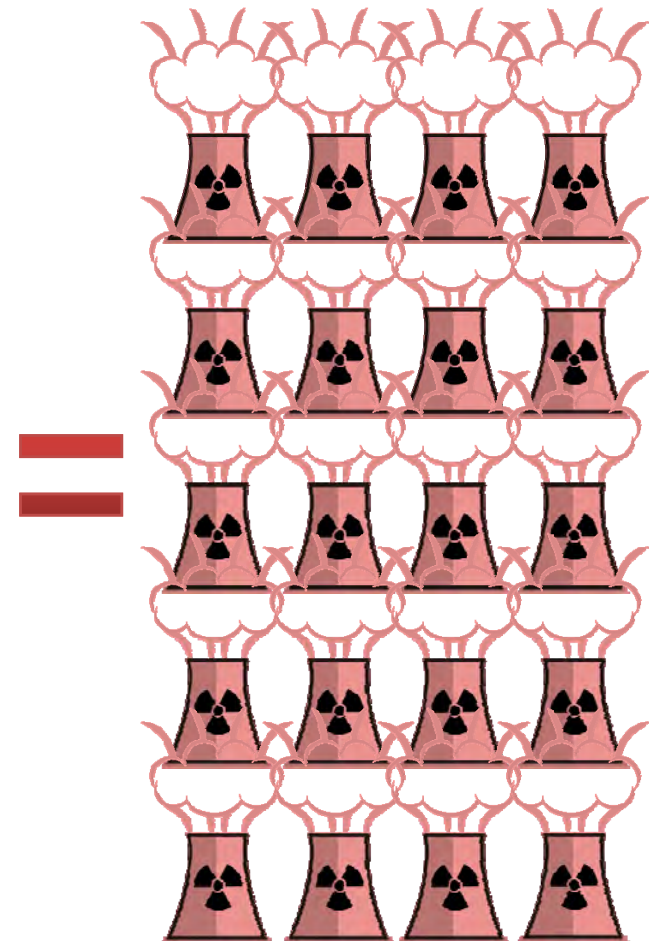
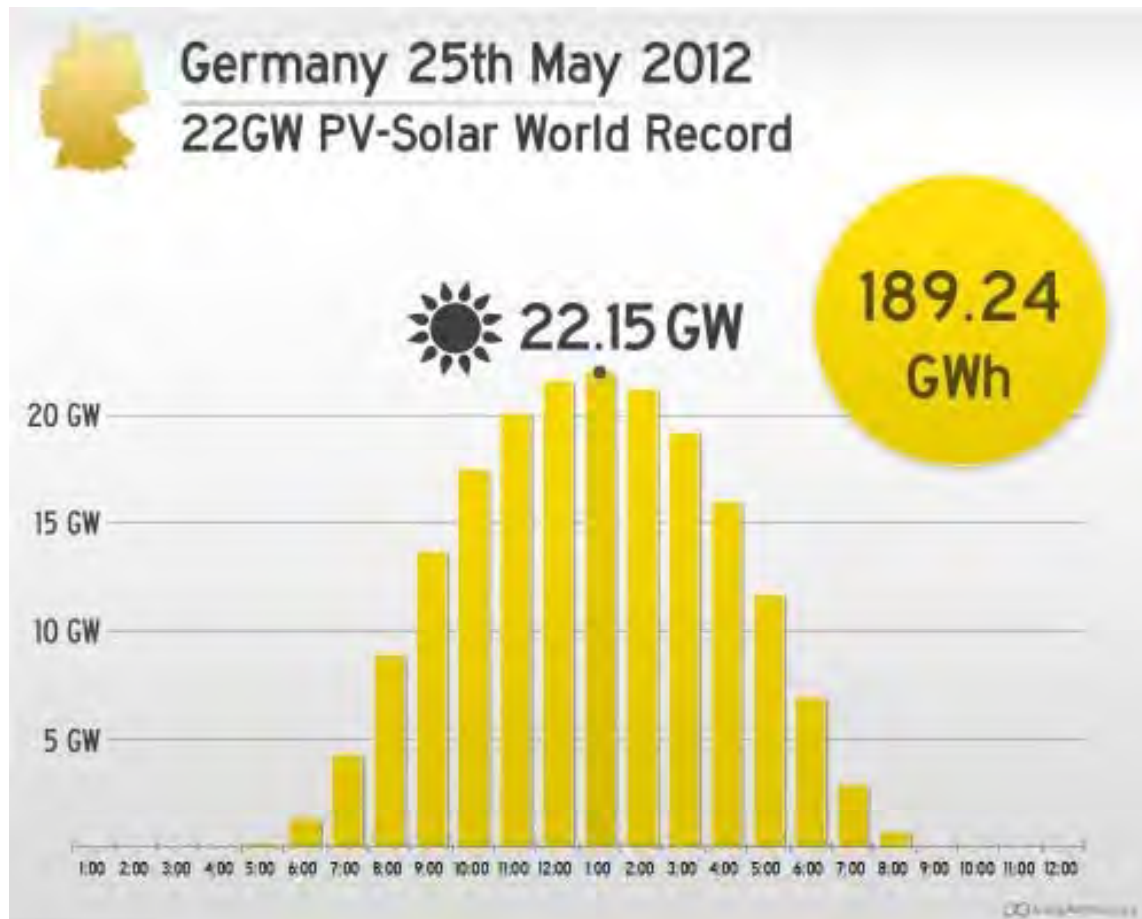


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# Marketing Prospect

- Reference Germany as present time
- Germany by mid 2012, solar plants' electricity production reach 22 GW or 22,000 MW equal to 20 Nuclear Plants

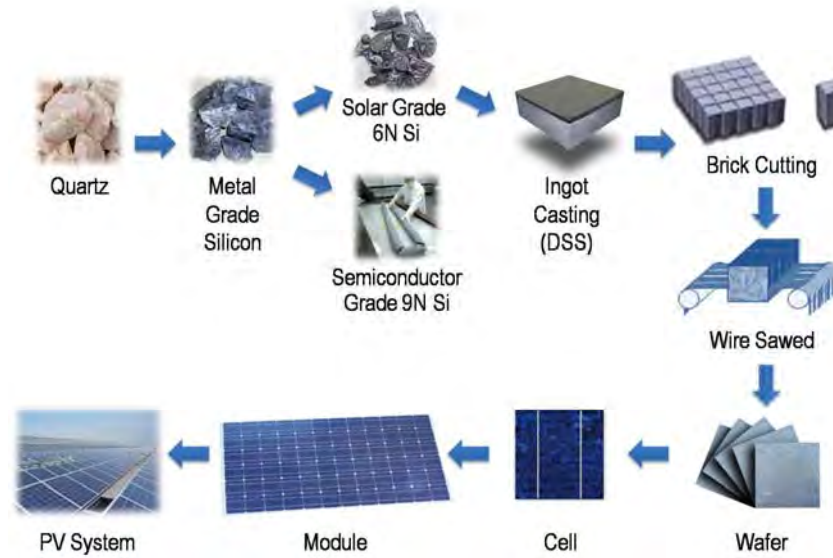


# Marketing Prospect

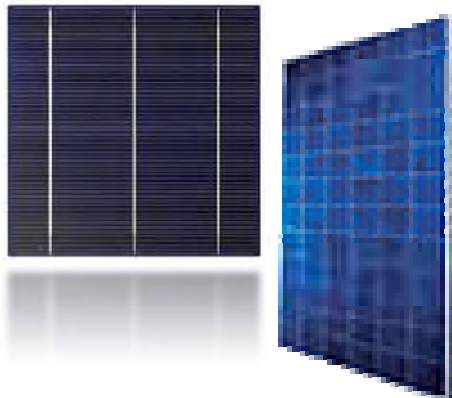


- Our aim is to concentrate in Rooftop installation where by the residential and commercial customers are our targets with affordable installation cost by available local services team.
- For small Solar Farms (VSPP) should be our secondary choice.

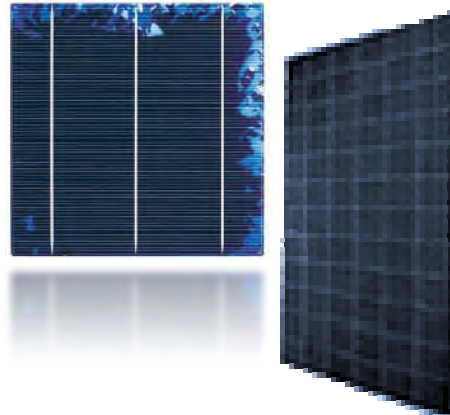
# Variety of Choices



Multicrystalline (Poly)



Quasi-mono



Monocrystalline



# Are We Ready for AEC 2015?



***Time is running up!!***

Thailand's local solar industry shall be promoted and ready for upcoming challenges, energy policy should be cleared and supportive to local manufacturers, when we open market to The ASEAN Economic Community (AEC) in 2015



*“Clean Energy from the Sun,  
is the Future Energy for Our Country”*



Thanks for your attention!

Contact:  
Chaiyuth Kiatpinyo  
Managing Director  
Solar Synergy Co.,Ltd.

[chaiyuth@mitracom.co.th](mailto:chaiyuth@mitracom.co.th)  
+(66) 02 971 6474

